## Acta Crystallographica Section E

## Structure Reports

Online
ISSN 1600-5368

## 1,4-Bis(dimethylsilyl)-2,5-diphenylbenzene

Lei Fang, ${ }^{\text {a,b }}$ Rui Wang, ${ }^{\text {a,b }}$ Li-Min Chen, ${ }^{\text {a }}$ Cai-Hong Xu ${ }^{\text {a }}$ and Shu-Hong Lic

${ }^{\text {a }}$ Beijing National Laboratory for Molecular Sciences (BNLMS), Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, People's Republic of China,
${ }^{\text {b }}$ Graduate School of the Chinese Academy of Sciences, Beijing 100049, People's Republic of China, and ${ }^{\mathrm{c}}$ School of Chemical and Environmental Engineering, Beijing Technology and Business University, Beijing 100037, People's Republic of China Correspondence e-mail: caihong@iccas.ac.cn

Received 23 February 2010; accepted 23 March 2010
Key indicators: single-crystal X-ray study; $T=173 \mathrm{~K}$; mean $\sigma(\mathrm{C}-\mathrm{C})=0.003 \AA$; $R$ factor $=0.055 ; w R$ factor $=0.118$; data-to-parameter ratio $=20.0$.

The molecule of the title compound, $\mathrm{C}_{22} \mathrm{H}_{26} \mathrm{Si}_{2}$, is centrosymmetric. The dihedral angle between the central benzene ring and its phenyl substituents is $67.7(2)^{\circ}$. The crystal packing is stabilized by van der Waals forces.

## Related literature

For investigations on the effect of silyl substituents on the
photophysics of $p$-terphenyls, see: Feng et al. (2007).



## Experimental

Crystal data
$\mathrm{C}_{22} \mathrm{H}_{26} \mathrm{Si}_{2}$
$M_{r}=346.61$
Monoclinic, $C 2 / c$
$a=14.8966$ (3) £
$b=6.0132$ (1) $\AA$
$c=26.1211$ (6) $\AA$
$\beta=123.166$ (1) ${ }^{\circ}$

$$
\begin{aligned}
& V=1958.64(7) \AA^{3} \\
& Z=4 \\
& \text { Mo } K \alpha \text { radiation } \\
& \mu=0.18 \mathrm{~mm}^{-1} \\
& T=173 \mathrm{~K} \\
& 0.56 \times 0.39 \times 0.11 \mathrm{~mm}
\end{aligned}
$$

## Data collection

Rigaku R-AXIS RAPID IP areadetector diffractometer
Absorption correction: multi-scan (ABSCOR; Higashi, 1995) $T_{\text {min }}=0.905, T_{\text {max }}=0.980$

## Refinement

$R\left[F^{2}>2 \sigma\left(F^{2}\right)\right]=0.055$
$w R\left(F^{2}\right)=0.118$
$S=1.22$
2220 reflections

Data collection: RAPID-AUTO (Rigaku, 2001); cell refinement: RAPID-AUTO; data reduction: RAPID-AUTO; program(s) used to solve structure: SHELXS97 (Sheldrick, 2008); program(s) used to refine structure: SHELXL97 (Sheldrick, 2008); molecular graphics: SHELXTL (Sheldrick, 2008); software used to prepare material for publication: SHELXL97.

This work was supported by the National Science Foundation of China (NSFC, Nos. 50673094 and 20774102).

Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: GK2260).

## References

Feng, X., Pisula, W. \& Müllen, K. (2007). J. Am. Chem. Soc. 129, 14116-14117. Higashi, T. (1995). ABSCOR. Rigaku Corporation, Tokyo, Japan. Rigaku (2001). RAPID-AUTO. Rigaku Corporation, Tokyo, Japan. Sheldrick, G. M. (2008). Acta Cryst. A64, 112-122.

# supporting information 

Acta Cryst. (2010). E66, o970 [doi:10.1107/S1600536810010913]

## 1,4-Bis(dimethylsilyl)-2,5-diphenylbenzene

Lei Fang, Rui Wang, Li-Min Chen, Cai-Hong Xu and Shu-Hong Li

## S1. Comment

As part of our ongoing investigation on the effect of silyl substituents on the photophysics of $p$-terphenyls, we present the title compound bearing silyl substituents at the central phenyl ring ( 2,5 -positions). Though analogues of the title compound were reported elsewhere (Feng et al., 2007), their structures were not fully studied. The molecular structure of the title compound is shown in Fig.1. It is centrosymmetric, the centroid of the central benzene ring is located on an inversion center at $0,1,0$. The dihedral angle between the benzene ring and phenyl substituents is $67.7(2)^{\circ}$. The crystal packing is mainly stabilized by van der Waals forces.

## S2. Experimental

A solution of 2,5-dibromo-1,4-diphenylbenzene ( $120 \mathrm{mg}, 0.31 \mathrm{mmol}$ ) in anhydrous THF ( 10 ml ) was added dropwise to a hexane solution of $\mathrm{n}-\mathrm{BuLi}(2.5 \mathrm{M}, 0.44 \mathrm{ml}, 1.08 \mathrm{mmol})$ dropwise at $-78^{\circ} \mathrm{C}$. The reaction mixture was stirred for 1 h and dimethylchlorosilane ( $118 \mathrm{mg}, 1.24 \mathrm{mmol}$ ) was added via syringe at the same temperature and the mixture was allowed to warm to room temperature and stirred overnight. After being quenched with saturated $\mathrm{NaHCO}_{3}$ solution, the mixture was extracted with $\mathrm{Et}_{2} \mathrm{O}$. The organic layer was washed with brine, dried over anhydrous $\mathrm{MgSO}_{4}$, filtered, and concentrated under reduced pressure. The mixture was passed through a silica gel column with hexane as an eluent, followed by further purification by recrystallization from ethanol to give 98 mg of the white product in $91 \%$ yield.

## S3. Refinement

All H -atoms were located in electron-density difference maps. Carbon-bound H atoms were placed geometrically in idealized positions and refined using a riding model with $\mathrm{C}-\mathrm{H}$ (methyl) $0.98, \mathrm{C}-\mathrm{H}$ (aromatic) $0.95 \AA$ and with $\mathrm{U}_{\text {iso }}(\mathrm{H})$ $=1.2 \mathrm{U}_{\mathrm{eq}}(\mathrm{C})$. Located in the electron-density difference map H atom from the silyl group was refined using riding model with $\mathrm{U}_{\text {iso }}(\mathrm{H})=1.2 \mathrm{U}_{\mathrm{eq}}(\mathrm{Si})$.


Figure 1
The structure of the title compound showing $50 \%$ probability displacement ellipsoids and the atom-numbering scheme.
The unlabelled atoms can be generated by the symmetry operation $-\mathrm{x},-\mathrm{y}+2,-\mathrm{z}$.

## 1,4-Bis(dimethylsilyl)-2,5-diphenylbenzene

## Crystal data

$\mathrm{C}_{22} \mathrm{H}_{26} \mathrm{Si}_{2}$
$M_{r}=346.61$
Monoclinic, $C 2 / c$
Hall symbol: -C 2yc
$a=14.8966$ (3) Å
$b=6.0132$ (1) $\AA$
$c=26.1211(6) \AA$
$\beta=123.166(1)^{\circ}$
$V=1958.64(7) \AA^{3}$
$Z=4$

## Data collection

Rigaku R-AXIS RAPID IP area-detector diffractometer
Radiation source: rotating anode
Graphite monochromator
$\omega$ scans at fixed $\chi=45^{\circ}$
Absorption correction: multi-scan (ABSCOR; Higashi, 1995)
$T_{\text {min }}=0.905, T_{\text {max }}=0.980$
$F(000)=744$
$D_{\mathrm{x}}=1.175 \mathrm{Mg} \mathrm{m}^{-3}$
Mo $K \alpha$ radiation, $\lambda=0.71073 \AA$
Cell parameters from 4032 reflections
$\theta=2.7-27.5^{\circ}$
$\mu=0.18 \mathrm{~mm}^{-1}$
$T=173 \mathrm{~K}$
Plate, colorless
$0.56 \times 0.39 \times 0.11 \mathrm{~mm}$

4032 measured reflections
2220 independent reflections
2009 reflections with $I>2 \sigma(I)$
$R_{\text {int }}=0.028$
$\theta_{\text {max }}=27.5^{\circ}, \theta_{\text {min }}=2.7^{\circ}$
$h=-19 \rightarrow 19$
$k=-7 \rightarrow 7$
$l=-33 \rightarrow 33$

## Refinement

Refinement on $F^{2}$
Least-squares matrix: full
$R\left[F^{2}>2 \sigma\left(F^{2}\right)\right]=0.055$
$w R\left(F^{2}\right)=0.118$
$S=1.22$
2220 reflections
111 parameters
0 restraints
Primary atom site location: structure-invariant direct methods

Secondary atom site location: difference Fourier
$\quad$ map
Hydrogen site location: inferred from
$\quad$ neighbouring sites
H -atom parameters constrained
$w=1 /\left[\sigma^{2}\left(F_{\mathrm{o}}^{2}\right)+(0.0432 P)^{2}+2.0232 P\right]$
where $P=\left(F_{\mathrm{o}}^{2}+2 F_{\mathrm{c}}^{2}\right) / 3$
$(\Delta / \sigma)_{\max }<0.001$
$\Delta \rho_{\max }=0.40$ e $\AA^{-3}$
$\Delta \rho_{\min }=-0.22$ e $\AA^{-3}$

## Special details

Geometry. All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.
Refinement. Refinement of $F^{2}$ against ALL reflections. The weighted $R$-factor wR and goodness of fit $S$ are based on $F^{2}$, conventional $R$-factors $R$ are based on $F$, with $F$ set to zero for negative $F^{2}$. The threshold expression of $F^{2}>2 \sigma\left(F^{2}\right)$ is used only for calculating $R$-factors(gt) etc. and is not relevant to the choice of reflections for refinement. $R$-factors based on $F^{2}$ are statistically about twice as large as those based on $F$, and $R$ - factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters ( $\hat{A}^{2}$ )

|  | $x$ | $y$ | $z$ | $U_{\text {iss }}{ }^{*} U_{\mathrm{eq}}$ |
| :--- | :--- | :--- | :--- | :--- |
| Si1 | $-0.03046(4)$ | $0.64331(9)$ | $0.08538(2)$ | $0.02208(16)$ |
| H1 | 0.0590 | 0.5194 | 0.1223 | $0.026^{*}$ |
| C1 | $-0.00698(14)$ | $0.8349(3)$ | $0.03690(8)$ | $0.0207(4)$ |
| C2 | $-0.09110(15)$ | $0.8753(3)$ | $-0.02358(8)$ | $0.0220(4)$ |
| H2 | -0.1545 | 0.7887 | -0.0403 | $0.026^{*}$ |
| C3 | $0.08631(14)$ | $0.9637(3)$ | $0.06040(8)$ | $0.0202(4)$ |
| C4 | $0.18299(14)$ | $0.9316(3)$ | $0.12353(8)$ | $0.0208(4)$ |
| C5 | $0.21644(16)$ | $1.0962(3)$ | $0.16753(9)$ | $0.0276(4)$ |
| H5 | 0.1762 | 1.2298 | 0.1578 | $0.033^{*}$ |
| C6 | $0.30788(17)$ | $1.0685(4)$ | $0.22563(9)$ | $0.0314(5)$ |
| H6 | 0.3292 | 1.1819 | 0.2555 | $0.038^{*}$ |
| C7 | $0.36813(15)$ | $0.8762(4)$ | $0.24023(8)$ | $0.0285(4)$ |
| H7 | 0.4314 | 0.8582 | 0.2798 | $0.034^{*}$ |
| C8 | $0.33562(16)$ | $0.7103(4)$ | $0.19677(9)$ | $0.0310(5)$ |
| H8 | 0.3763 | 0.5773 | 0.2067 | $0.037^{*}$ |
| C9 | $0.24395(16)$ | $0.7377(3)$ | $0.13896(8)$ | $0.0261(4)$ |
| H9 | 0.2223 | 0.6231 | 0.1094 | $0.031^{*}$ |
| C10 | $-0.0605(2)$ | $0.8174(4)$ | $0.13337(10)$ | $0.0375(5)$ |
| H10A | -0.1249 | 0.9065 | 0.1068 | $0.056^{*}$ |
| H10B | 0.0002 | 0.9164 | 0.1592 | $0.056^{*}$ |
| H10C | -0.0726 | 0.7209 | 0.1593 | $0.056^{*}$ |
| C11 | $-0.14236(19)$ | $0.4490(4)$ | $0.03752(10)$ | $0.0377(5)$ |
| H11A | -0.1565 | 0.3595 | 0.0637 | $0.057^{*}$ |
| H11B | -0.1230 | 0.3509 | 0.0151 | $0.057^{*}$ |
| H11C | -0.2068 | 0.5338 | 0.0084 |  |

Atomic displacement parameters $\left(\AA^{2}\right)$

|  | $U^{11}$ | $U^{22}$ | $U^{\beta 3}$ | $U^{12}$ | $U^{13}$ | $U^{23}$ |
| :--- | :--- | :--- | :--- | :--- | :--- | :--- |
| Si1 | $0.0233(3)$ | $0.0233(3)$ | $0.0197(3)$ | $0.0028(2)$ | $0.0118(2)$ | $0.0051(2)$ |
| C1 | $0.0221(9)$ | $0.0217(9)$ | $0.0194(8)$ | $0.0021(7)$ | $0.0120(7)$ | $0.0018(7)$ |
| C2 | $0.0213(9)$ | $0.0241(9)$ | $0.0199(8)$ | $-0.0012(7)$ | $0.0110(7)$ | $-0.0005(7)$ |
| C3 | $0.0208(9)$ | $0.0228(9)$ | $0.0162(8)$ | $0.0024(7)$ | $0.0096(7)$ | $0.0009(7)$ |
| C4 | $0.0190(8)$ | $0.0251(9)$ | $0.0170(8)$ | $0.0005(7)$ | $0.0090(7)$ | $0.0016(7)$ |
| C5 | $0.0268(10)$ | $0.0246(10)$ | $0.0242(9)$ | $0.0041(8)$ | $0.0094(8)$ | $-0.0009(8)$ |
| C6 | $0.0315(11)$ | $0.0333(11)$ | $0.0202(9)$ | $0.0000(9)$ | $0.0082(8)$ | $-0.0051(8)$ |
| C7 | $0.0202(9)$ | $0.0406(12)$ | $0.0174(8)$ | $0.0028(8)$ | $0.0056(7)$ | $0.0015(8)$ |
| C8 | $0.0259(10)$ | $0.0365(11)$ | $0.0242(9)$ | $0.0115(9)$ | $0.0096(8)$ | $0.0038(9)$ |
| C9 | $0.0276(10)$ | $0.0274(10)$ | $0.0199(9)$ | $0.0051(8)$ | $0.0108(8)$ | $-0.0020(8)$ |
| C10 | $0.0482(13)$ | $0.0381(12)$ | $0.0341(11)$ | $0.0045(10)$ | $0.0275(11)$ | $0.0008(10)$ |
| C11 | $0.0454(13)$ | $0.0356(12)$ | $0.0367(12)$ | $-0.0103(10)$ | $0.0254(11)$ | $-0.0035(10)$ |

Geometric parameters ( $A,{ }^{\circ}$ )

| Si1-C11 | 1.851 (2) | C6-C7 | 1.383 (3) |
| :---: | :---: | :---: | :---: |
| Si1-C10 | 1.866 (2) | C6-H6 | 0.9500 |
| Sil-C1 | 1.8812 (19) | C7-C8 | 1.385 (3) |
| Si1-H1 | 1.3623 | C7-H7 | 0.9500 |
| C1-C2 | 1.400 (2) | C8-C9 | 1.384 (3) |
| C1-C3 | 1.405 (3) | C8-H8 | 0.9500 |
| C2-C3 ${ }^{\text {i }}$ | 1.394 (3) | C9-H9 | 0.9500 |
| C2-H2 | 0.9500 | C10-H10A | 0.9800 |
| C3-C2 ${ }^{\text {i }}$ | 1.394 (3) | C10-H10B | 0.9800 |
| C3-C4 | 1.494 (2) | C10-H10C | 0.9800 |
| C4-C5 | 1.386 (3) | C11-H11A | 0.9800 |
| C4-C9 | 1.395 (3) | C11-H11B | 0.9800 |
| C5-C6 | 1.387 (3) | C11-H11C | 0.9800 |
| C5-H5 | 0.9500 |  |  |
| C11-Si1-C10 | 110.47 (11) | C5-C6-H6 | 119.9 |
| C11-Si1-C1 | 111.24 (9) | C6-C7-C8 | 119.55 (17) |
| C10-Si1-C1 | 108.04 (10) | C6-C7-H7 | 120.2 |
| C11-Si1-H1 | 107.7 | C8-C7-H7 | 120.2 |
| C10-Si1-H1 | 109.4 | C9-C8-C7 | 120.16 (19) |
| C1—Si1-H1 | 110.0 | C9-C8-H8 | 119.9 |
| C2-C1-C3 | 117.29 (16) | C7-C8-H8 | 119.9 |
| $\mathrm{C} 2-\mathrm{C} 1-\mathrm{Si} 1$ | 118.99 (14) | C8-C9-C4 | 120.83 (18) |
| C3-C1-Si1 | 123.17 (13) | C8-C9-H9 | 119.6 |
| C3--C2-C1 | 123.17 (17) | C4-C9-H9 | 119.6 |
| $\mathrm{C} 3-\mathrm{C} 2-\mathrm{H} 2$ | 118.4 | Sil-C10-H10A | 109.5 |
| $\mathrm{C} 1-\mathrm{C} 2-\mathrm{H} 2$ | 118.4 | Si1-C10-H10B | 109.5 |
| C2--C3-C1 | 119.54 (16) | H10A-C10-H10B | 109.5 |
| C2--C3-C4 | 117.97 (16) | Sil-C10-H10C | 109.5 |
| C1-C3-C4 | 122.47 (16) | H10A-C10-H10C | 109.5 |


| C5-C4-C9 | 118.37 (16) | H10B-C10-H10C | 109.5 |
| :---: | :---: | :---: | :---: |
| C5-C4-C3 | 121.00 (17) | Sil-C11-H11A | 109.5 |
| C9-C4-C3 | 120.59 (17) | Si1-C11-H11B | 109.5 |
| C4-C5-C6 | 120.91 (18) | H11A-C11-H11B | 109.5 |
| C4-C5-H5 | 119.5 | Si1-C11-H11C | 109.5 |
| C6-C5-H5 | 119.5 | H11A-C11-H11C | 109.5 |
| C7-C6- 55 | 120.18 (19) | H11B-C11-H11C | 109.5 |
| C7-C6-H6 | 119.9 |  |  |
| C11-Si1-C1-C2 | 23.44 (19) | C1-C3-C4-C5 | -114.5 (2) |
| C10-Si1-C1-C2 | -97.97 (17) | C2--C3-C4-C9 | -110.8(2) |
| C11-Si1-C1-C3 | -165.30 (16) | C1-C3-C4-C9 | 67.7 (2) |
| C10-Si1-C1-C3 | 73.29 (18) | C9-C4-C5-C6 | -0.4 (3) |
| $\mathrm{C} 3-\mathrm{C} 1-\mathrm{C} 2-\mathrm{C} 3^{\text {i }}$ | -0.6 (3) | C3-C4-C5-C6 | -178.25 (18) |
| $\mathrm{Si} 1-\mathrm{C} 1-\mathrm{C} 2-\mathrm{C} 3^{\text {i }}$ | 171.16 (14) | C4-C5-C6-C7 | 0.9 (3) |
| $\mathrm{C} 2-\mathrm{C} 1-\mathrm{C} 3-\mathrm{C} 2^{\text {i }}$ | 0.6 (3) | C5-C6-C7-C8 | -1.0 (3) |
| $\mathrm{Si} 1-\mathrm{C} 1-\mathrm{C} 3-\mathrm{C} 2^{\text {i }}$ | -170.81 (14) | C6-C7-C8-C9 | 0.6 (3) |
| $\mathrm{C} 2-\mathrm{C} 1-\mathrm{C} 3-\mathrm{C} 4$ | -177.92 (17) | C7-C8-C9-C4 | 0.0 (3) |
| Si1-C1-C3-C4 | 10.7 (3) | C5-C4-C9-C8 | 0.0 (3) |
| C2 ${ }^{\text {i }}$ C $3-\mathrm{C} 4-\mathrm{C} 5$ | 67.0 (2) | C3-C4-C9-C8 | 177.82 (19) |

Symmetry code: (i) $-x,-y+2,-z$.

